NSN 5962-01-451-1659

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Vmisc e/i fscm 80132
Features Provided:
Monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Terminal Surface Treatment:
Solder
Product Name:
Microcircuits, memory, digital, cmos 8k x 8-bit eeprom, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.3 volts input and 6.0 volts input
Time Rating Per Chacteristic:
300.00 nanoseconds af output megawatts
Memory Device Type:
Eeprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0